

**FULLY DECODED 2048 BIT ELECTRICALLY ERASABLE AND PROGRAMMABLE READ ONLY MEMORY**

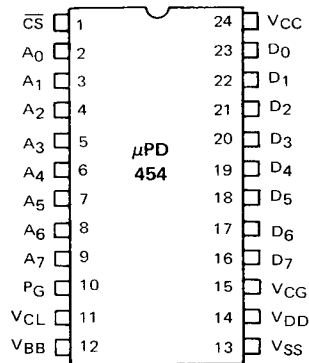
**DESCRIPTION** The  $\mu$ PD454 EEPROM, a 256 Words x 8 Bits Read Only Memory, is designed for rapid development of microcomputer systems. The ability to electrically program, erase, and reprogram the  $\mu$ PD454 provides a fast and convenient means of debugging both hardware and software designs.

The  $\mu$ PD454 is pin for pin compatible with NEC's  $\mu$ PD464 mask programmed ROM.

**FEATURES**

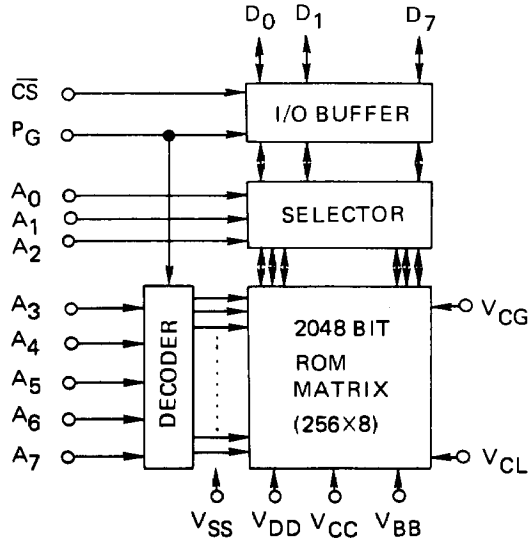
- Electrically Erasable and Programmable
- Fully Decoded, 256 Words x 8 Bits Organization
- Access Time 800 ns Max
- Low Power: 245 mW (Typ.) in Read Operation  
 670 mW (Typ.) in Programming Operation
- Fast Programming and Erasure Speed
- Low Power for Programming and Erasure
- Static, No Clock Required
- Input/Output TTL Compatible for Read and Programming Operation
- Three-State Output, OR-Tie Capability
- N-Channel MOS Fabrication
- Two Power Supplies, +12V and +5V for Read Operation
- 24 Pin Ceramic DIP

**PIN CONFIGURATION**



Rev/1





Operating Temperature	-10°C to +70°C
Storage Temperature	-40°C to +125°C
All Output Voltages	-0.3 to +11 Volts <sup>①</sup>
All Input Voltages	-0.3 to +11 Volts <sup>①</sup>
Supply Voltage VDD	-0.3 to +15 Volts <sup>①</sup>
Supply Voltage VCC	-0.3 to +7 Volts <sup>①</sup>
Supply Voltage VBB	VSS to -7 Volts <sup>②</sup>
Supply Voltage PG	-0.3 to +30 Volts <sup>① ②</sup>
Supply Voltage VCL	-0.3 to +43 Volts <sup>① ②</sup>
Supply Voltage VCG	-44 to +30 Volts <sup>① ②</sup>

**ABSOLUTE MAXIMUM RATINGS\***

- Notes: ① Relative to V<sub>BB</sub>.  
 ② Data in the memory cell is not guaranteed to be preserved.  
 Specifies ratings which will not cause permanent damage to the device.

COMMENT: Stress above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

\*T<sub>a</sub> = 25°C

**CAPACITANCE**

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Input Capacitance	C <sub>IN</sub>			10	pF	f = 1 MHz
Output Capacitance	C <sub>OUT</sub>			15	pF	f = 1 MHz

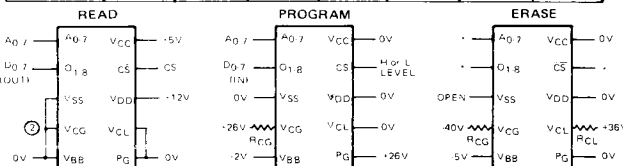
PIN DEFINITION

		PIN		FUNCTION
NO.	SYMBOL	NAME		
1	CS	CHIP SELECT		Chip selection, active low
2-9	A <sub>0</sub> -A <sub>7</sub>	ADDRESS BUS		Memory address
10	P <sub>G</sub>	+26V (TYP) Power Supply		Power supply for programming operation
11	V <sub>CL</sub>	+36V (TYP) Power Supply		Power supply for erasing operations
12	V <sub>BB</sub>	Substrate Power Supply		Power supply
13	V <sub>SS</sub>	GROUND		Ground Reference
14	V <sub>DD</sub>	+12V Power Supply		Power supply for read operations
15	V <sub>CG</sub>	-44 to +30 Power Supply		Power supply for control of programming and erasure operations
16-23	D <sub>7</sub> -D <sub>0</sub>	Data Input/Output		Data In for programming operations. Data Output for read operations.
24	V <sub>CC</sub>	+5V Power Supply		Power supply for read operations

SUPPLY VOLTAGES

Typical values. Unit: Voltage.

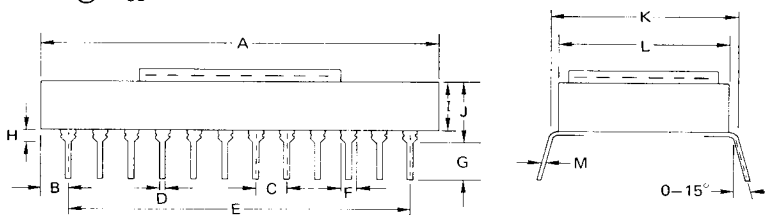
PIN MODE	V <sub>DD</sub> (14)	V <sub>CC</sub> (24)	V <sub>BB</sub> (14)	P <sub>G</sub> (10)	V <sub>CL</sub> (11)	V <sub>CG</sub> (15)	V <sub>SS</sub> (13)
Read	+12	+5	0	0	0	0	0
Program	0	0	2	+26	0	+26	0
Erase	0	0	5	0	+36	40	Open
Verify "0"	+12	+5		0	0	+3	0
Verify "1"	+12	+5		0	0	+3	0



Notes: \* = Either High or Low Level, or Open.

- ① R<sub>CG</sub> and R<sub>CL</sub> are Protection Resistors  
R<sub>CG</sub> = 10 kΩ ± 10%, 1/4W  
R<sub>CL</sub> = 200Ω ± 10%, 10W
- ② R<sub>CG</sub> may be left connected in Read Mode

PACKAGE OUTLINE  
μPD454D



ITEM	MILLIMETERS	INCHES
A	32.5 MAX	1.28 MAX
B	2.28	0.09
C	2.54	0.1
D	0.5 ± 0.1	0.02 ± 0.004
E	27.94	1.1
F	1.20 MIN	0.047 MIN
G	3.2 MIN	0.126 MIN
H	1.0 MIN	0.04 MIN
I	4.2 MAX	0.165 MAX
J	5.2 MAX	0.205 MAX
K	15.24	0.6
L	13.9	0.55
M	0.30 ± 0.1	0.012 ± 0.004



# μ PD454

$T_a = -10$  to  $+70^\circ\text{C}$ ,  $V_{DD} = +12\text{V} \pm 5\%$ ,  $V_{CC} = +5\text{V} \pm 5\%$ ,  
 $V_{BB} = P_G = V_{CL} = V_{CG} = V_{SS} = 0\text{V}$

## READ OPERATION DC CHARACTERISTICS

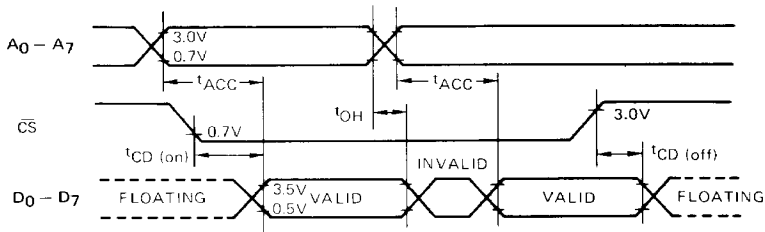
PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Input High Voltage	$V_{IH}$	3.0		$V_{CC}$	V	
Input Low Voltage	$V_{IL}$	0		0.7	V	
Output High Voltage	$V_{OH}$	3.5			V	$I_{OH} = -2.0\text{ mA}$
Output Low Voltage	$V_{OL}$			0.5	V	$I_{OL} = 1.7\text{ mA}$
Input Leakage Current High	$I_{L IH}$			+10	$\mu\text{A}$	$V_I = +3.0\text{V}$
Input Leakage Current Low	$I_{L IL}$			-10	$\mu\text{A}$	$V_I = +0.7\text{V}$
Output Leakage Current High	$I_{LOH}$			+100	$\mu\text{A}$	$\overline{CS} = "1"$ $V_O = 3.5\text{V}$
Output Leakage Current Low	$I_{LOL}$			-10	$\mu\text{A}$	$\overline{CS} = "1"$ $V_O = 0.4\text{V}$
$V_{DD}$ Supply Current	$I_{DD}$		20		mA	
$V_{CC}$ Supply Current	$I_{CC}$			0.3	mA	with no load

$T_a = -10$  to  $+70^\circ\text{C}$ ,  $V_{DD} = +12\text{V} \pm 5\%$ ,  $V_{CC} = +5\text{V} \pm 5\%$ ,  
 $V_{BB} = P_G = V_{CL} = V_{CG} = V_{SS} = 0\text{V}$

## AC CHARACTERISTICS

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Access Time	$t_{ACC}$			800	ns	1 TTL + 100 pF
CS to Output On Delay	$t_{CD(on)}$			200	ns	
CS to Output Off Delay	$t_{CD(off)}$	0		200	ns	
Output Hold Time	$t_{OH}$	0			ns	

## TIMING WAVEFORMS



**PROGRAMMING OPERATION**

Before the μPD454 is programmed the device must be erased. All bit locations must contain a zero (0). The μPD454 programming procedure is word by word one word at a time.

**DC CHARACTERISTICS**

$T_a = 25^{\circ}\text{C} \pm 2^{\circ}\text{C}$ ,  $V_{DD} = V_{CC} = V_{SS} = V_{CL} = 0\text{V}$ ,  $\overline{\text{CS}} = \text{Either HIGH or LOW level}$ .

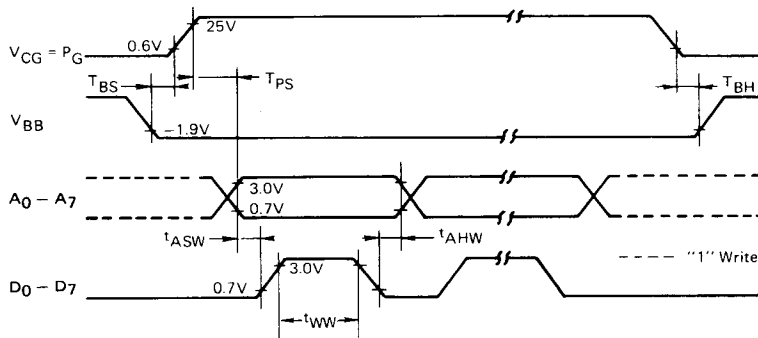
PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Input High Voltage	$V_{IH}$	3.0		$V_{CC}$	V	
Input Low Voltage	$V_{IL}$	0		0.7	V	
Supply Voltage	$V_{BB}$	-1.9	-2.0	-2.1	V	
Supply Voltage	$P_G$	25	26	27	V	
Supply Voltage	$V_{CG}$	25	26	27	V	through $R_{CG}$
Supply Current ( $V_{BB}$ )	$I_{BB}$		-8		mA	
Supply Current ( $P_G$ )	$I_G$		+25		mA	
Supply Current ( $V_{CG}$ )	$I_{CG}$			+10	μA	

**AC CHARACTERISTICS**

$T_a = 25^{\circ}\text{C} \pm 2^{\circ}\text{C}$ ,  $V_{DD} = V_{CC} = V_{SS} = V_{CL} = 0\text{V}$ ,  $\overline{\text{CS}} = \text{Either HIGH or LOW level}$ .

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Address Setup Time	$t_{ASW}$	10			μs	
Address Hold Time	$t_{AHW}$	10			μs	
Write Data Width	$t_{WW}$	20		100	ms	per one word
$V_{BB}$ Setup Time	$T_{BS}$	1.0			μs	
$V_{BB}$ Hold Time	$T_{BH}$	1.0			μs	
$P_G, V_{CG}$ Setup Time	$T_{PS}$	10			μs	

**TIMING WAVEFORMS**



# μ PD454

$T_a = 25^\circ\text{C} \pm 2^\circ\text{C}$ ,  $V_{DD} = V_{CC} = P_G = 0\text{V}$ ,  $V_{SS} = 0\text{V}$

$\overline{CS}$ ,  $A_0 - A_7$  and  $D_0 - D_7 = \text{Either HIGH or LOW level, or non-connected}$

## ERASURE OPERATION\*

### DC CHARACTERISTICS

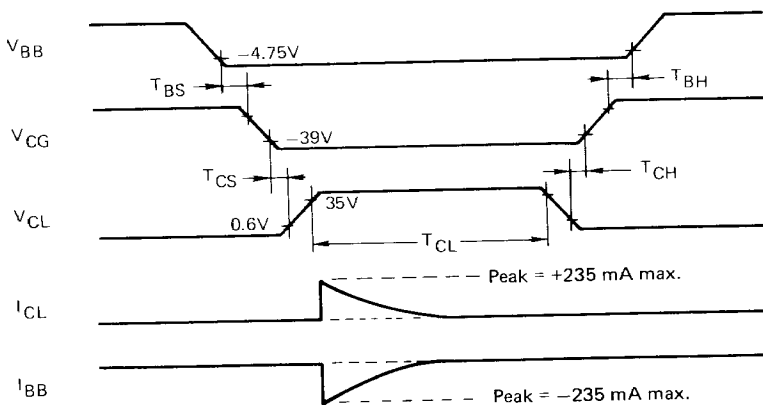
PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Supply Voltage	$V_{BB}$	-4.75	-5.0	-5.25	V	
Supply Voltage	$V_{CL}$	+35	+36	+37	V	through $R_{CL}$
Supply Voltage	$V_{CG}$	-39	-40	-41	V	through $R_{CG}$
Supply Current ( $V_{BB}$ )	$I_{BB}$			-235	mA	Initial peak current. See timing chart.
Supply Current ( $V_{CL}$ )	$I_{CL}$			-235	mA	
Supply Current ( $V_{CG}$ )	$I_{CG}$			-20	$\mu\text{A}$	

$T_a = 25^\circ\text{C} \pm 2^\circ\text{C}$ ,  $V_{DD} = V_{CC} = P_G = 0\text{V}$ ,  $V_{SS} = 0\text{V}$

$\overline{CS}$ ,  $A_0 - A_7$  and  $D_0 - D_7 = \text{Either HIGH or LOW level, or non-connected}$

### AC CHARACTERISTICS

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Clear Time	$T_{CL}$			60	sec	
$V_{BB}$ Setup Time	$T_{BS}$	0			$\mu\text{s}$	
$V_{BB}$ Hold Time	$T_{BH}$	0			$\mu\text{s}$	
$V_{CG}$ Setup Time	$T_{CS}$	1.0			$\mu\text{s}$	
$V_{CG}$ Hold Time	$T_{CH}$	1.0			$\mu\text{s}$	



### TIMING WAVEFORMS

Note: The supply currents  $I_{BB}$  and  $I_{CL}$  diminish to almost zero within  $T_{CL}$ .

\*Erasure operation clears all 2048 bits to Logic "0" simultaneously.

SP454-8-77-GY-CAT